ECE 595, Section 10 Numerical Simulations Lecture 24: Electronic Bandstructure Simulation Tools

Prof. Peter Bermel March 6, 2013

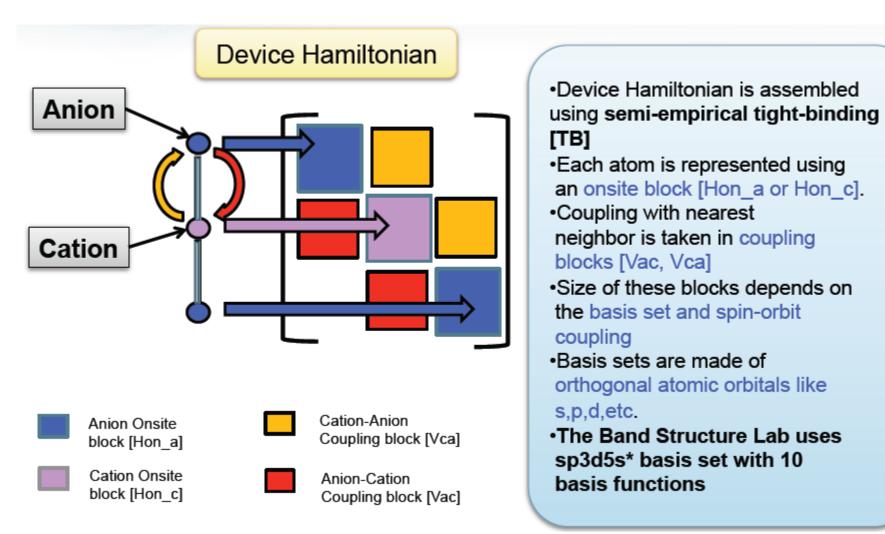
Recap from Monday

- Electronic bandstructure overview
- Calculational methods:
 - Nearly-free electron model
 - Wigner-Seitz method
 - Tight-binding
 - Pseudopotentials

Outline

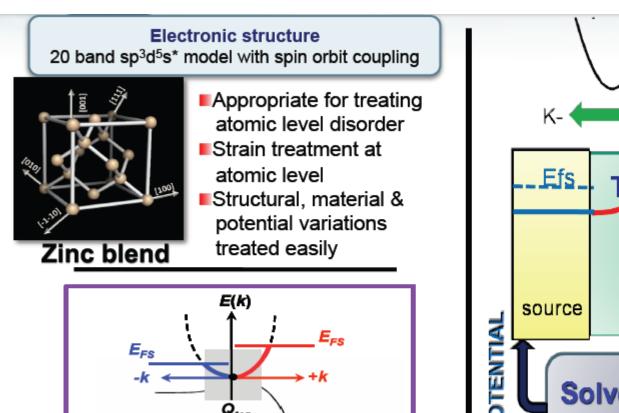
- Electronic bandstructure lab
 - Basic principles
 - Input Interface
 - Exemplary Outputs
- Density functional theory (DFT)
- DFT in Quantum ESPRESSO

Bandstructure Lab



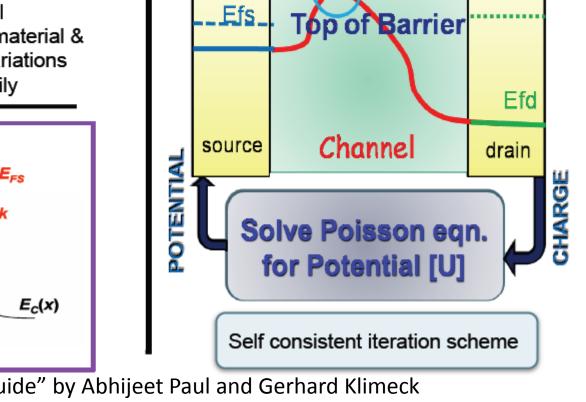
"First Time User Guide" by Abhijeet Paul and Gerhard Klimeck

Bandstructure Lab



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ballistic transport



"First Time User Guide" by Abhijeet Paul and Gerhard Klimeck

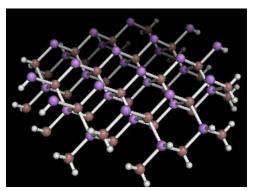
Bandstructure Lab: Input

- Step 1A: Choose basic geometry:
 - Nanowire (cylindrical 1D) also choose device cross-section
 - Ultra-thin body (2D-periodic) also choose body thickness
 - Bulk silicon (3D periodic)
- Step 1B: Choose material: Si, Ge, GaAs, or InAs

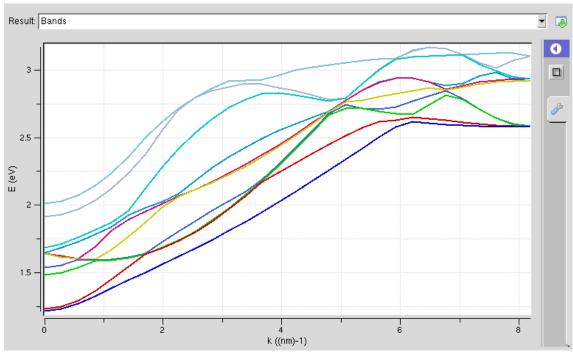
Bandstructure Lab: Input

- Step 2: Choose Device Physics:
 - Tight bonding model
 - Spin-orbit coupling
 - Dangling bond energy
 - Strain
- Step 3: Choose k-space of bandstructure
- Step 4: Choose k-interpolation, number of bands, and simulation venue

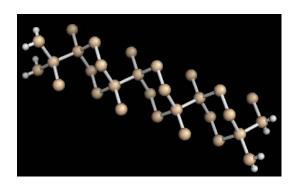
Bandstructure Lab: Output



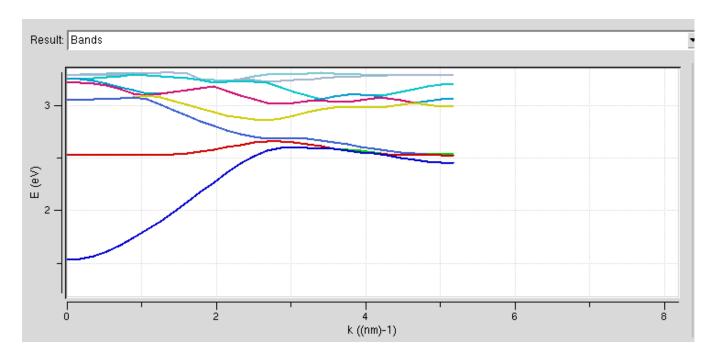
2D ultra-thin body (E_g =1.12 eV) Height z = 2.1 nm



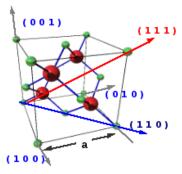
Electronic Bandstructure Lab:



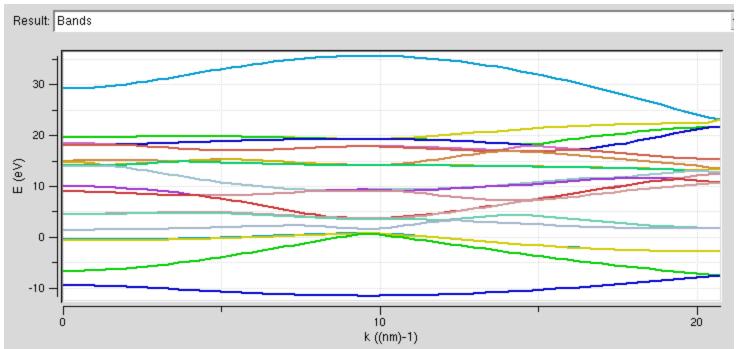
1D NW of InAs (E_g =0.17 eV) Circular cross-section, r = 2.1 nm



Bandstructure Lab: Output



3D periodic Ge Diamond lattice (E_g =0.67 eV)



Density Functional Theory

 Consider the N-electron Hamiltonian including electron-electron interactions:

$$\sum_{i} \left[-\frac{\hbar^2}{2m} \boldsymbol{\nabla}_{i}^{2} + V(\boldsymbol{r}_{i}) + \sum_{j} U(\boldsymbol{r}_{i}, \boldsymbol{r}_{j}) \right] \Psi = E \Psi$$

- Can try to solve using:
 - Hartree-Fock (treating electron-electron interactions as mean field
 - Post-Hartree-Fock (e.g., configuration interaction, coupled cluster, Moller-Plesset)
 - Density functional theory

Density Functional Theory

Write all functions in terms of particle density:

$$n(r) = N \int d^3r_2 \int d^3r_3 |\Psi(r, r_2, \dots, r_N)|^2$$

Now system energy becomes:

$$E[n] = T[n] + U[n] + \int d^3r V(r)n(r)$$

• Where T[n] and U[n] are universal functionals, and V[n] is a non-universal functional

Density Functional Theory

- Electron correlations mean greatest difficulty is in evaluating V[n]. Strategies include:
 - Local density approximation:

$$E_{XC}[n] = \int d^3r \, n(r) \, \epsilon_{XC}(n)$$

- Localized spin density approximation
- Generalized gradient approximation:

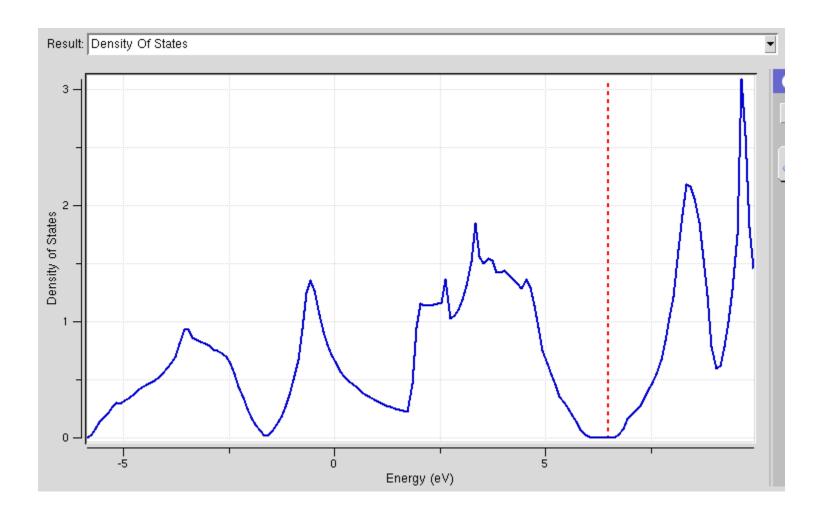
$$E_{XC}[n_{\uparrow},n_{\downarrow}] = \int d^3r \, n(r) \, \epsilon_{XC}(n_{\uparrow},n_{\downarrow},\nabla n_{\uparrow},\nabla n_{\downarrow})$$

Meta-generalized gradient approximation

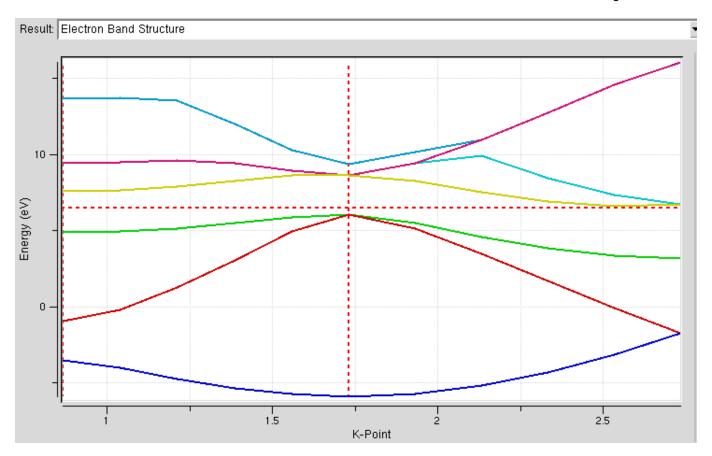
Quantum ESPRESSO: Input

- Step 1: Geometry
 - Atomic basis (e.g., 2 silicon atoms)
 - Lattice (e.g., diamond) and lattice constant a
- Step 2: Energy expression:
 - Approximation for E_{xc}
 - Bandstructure k-values
- Step 3: Phonon bands: yes or no
- Step 4: Bandstructure/DOS
 - Choose path for bandstructure
 - Choose energy range for density of states

Quantum ESPRESSO: Output



Quantum ESPRESSO: Output



- Displays bandgap of 0.6 eV, below true value
- GGA + quasi-Newton relaxation improve accuracy

Next Class

- Is on Friday, March 8
- Will conclude discussion of electronic bandstructure simulations